

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- *Low Forward Voltage.
- *Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- *150°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory
- Flammability Classification 94V-O

*ESD: 8KV(Min.) Human-Body Model * In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic	Symbol	SRF1645K	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
RMS Reverse Voltage	V _{R(RMS)}	31.5	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C =100 $^\circ$ C	I _{F(AV)}	8.0 16	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	16	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	125	A
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

ELECTRIAL CHARACTERISTICS

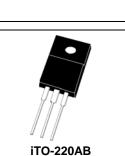
Characteristic	Symbol	SRF1645K	Unit
Maximum Instantaneous Forward Voltage (I _F =8 Amp T _C = 25℃) (I _F =8 Amp T _C = 100℃)	V _F	0.60 0.52	V
Typical Thermal Resistance junction to case	R _{θ j-c}	4.2	°C/w
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R	0.05 20	mA

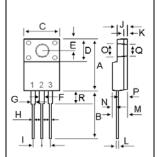


SCHOTTKY BARRIER RECTIFIERS

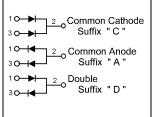
16 AMPERES

45 VOLTS





DIM	MILLIM	MILLIMETERS		
	MIN	MAX		
Α	14.90	15.15		
В	13.35	13.55		
С	10.00	10.10		
D	6.55	6.65		
E	2.65	2.75		
F	1.55	1.65		
G	1.15	1.25		
н	0.55	0.65		
1	2.50	2.60		
J	3.00	3.20		
ĸ	1.10	1.20		
L	0.55	0.65		
Μ	4.40	4.60		
N	1.15	1.25		
0	3.35	3.45		
Р	2.65	2.75		
Q	3.15	3.25		
R	3.60	3.80		

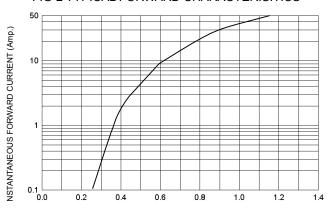


SRF1645K

САSE TEMPERATURE (°С)

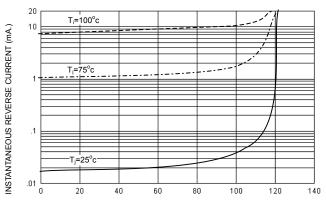
FIG-1 FORWARD CURRENT DERATING CURVE

FIG-2 TYPICAL FORWARD CHARACTERISITICS



FORWARD VOLTAGE (Volts)

FIG-3 TYPICAL REVERSE CHARACTERISTICS



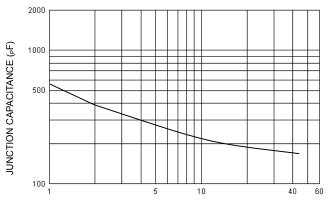
PERCENT OF RATED REVERSE VOLTAGE (%)

FIG-5 PEAK FORWARD SURGE CURRENT

150

NUMBER OF CYCLES AT 60 Hz

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)



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